

TECHNICAL DATA  
DATA SHEET 5510, REV. -

**HERMETIC SCHOTTKY RECTIFIER IN SMD-0.2**  
**Patented Thin Ceramic High Strength Package**  
**Very Low Forward Voltage Drop**

**Features:**

- Patented rugged package design (enhanced temperature/power cycling capability over standard SMD-0.2 package)
- Options to ground different nodes to lid (see ordering table)
- Very low forward voltage drop
- Low power loss, high efficiency, high surge capacity
- Guard ring for enhanced durability and long term reliability
- Guaranteed reverse avalanche characteristics

**Maximum Ratings**

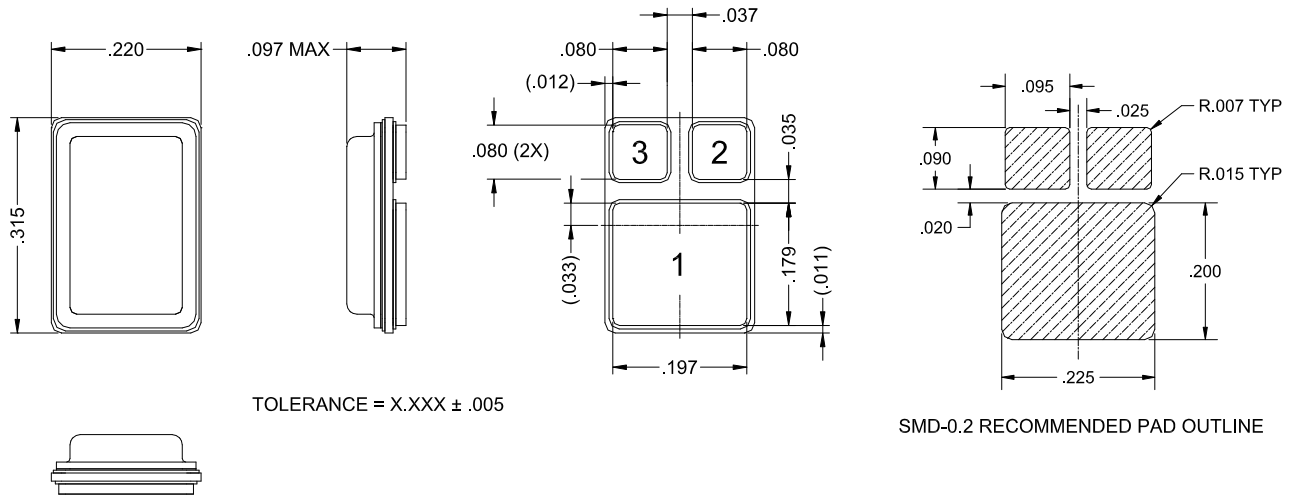
Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	100	V
Max. Average Forward Current	$I_{F(AV)}$	50% duty cycle, rectangular wave form (Single)	10	A
Max. Peak One Cycle Non-Repetitive Surge Current	$I_{FSM}$	8.3 ms, half Sine wave (per leg)	100	A
Maximum Thermal Resistance	$R_{\theta JC}$	-	6.4	°C/W
Max. Junction Temperature	$T_J$	-	-65 to +150	°C
Max. Storage Temperature	$T_{stg}$	-	-65 to +150	°C

**Electrical Characteristics**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg)	$V_{F1}$	@ 1A, Pulse, $T_J = 25\text{ °C}$	0.48	V
	$V_{F2}$	@ 3A, Pulse, $T_J = 25\text{ °C}$	0.56	
	$V_{F3}$	@ 5A, Pulse, $T_J = 25\text{ °C}$	0.63	
	$V_{F4}$	@ 7A, Pulse, $T_J = 25\text{ °C}$	0.69	
	$V_{F5}$	@ 10A, Pulse, $T_J = 25\text{ °C}$	0.76	
	$V_{F6}$	@ 1A, Pulse, $T_J = 125\text{ °C}$	0.37	V
	$V_{F7}$	@ 3A, Pulse, $T_J = 125\text{ °C}$	0.47	
	$V_{F8}$	@ 5A, Pulse, $T_J = 125\text{ °C}$	0.54	
	$V_{F9}$	@ 7A, Pulse, $T_J = 125\text{ °C}$	0.59	
	$V_{F10}$	@ 10A, Pulse, $T_J = 125\text{ °C}$	0.66	
	$V_{F11}$	@ 1A, Pulse, $T_J = -55\text{ °C}$	0.57	V
	$V_{F12}$	@ 3A, Pulse, $T_J = -55\text{ °C}$	0.63	
	$V_{F13}$	@ 5A, Pulse, $T_J = -55\text{ °C}$	0.69	
	$V_{F14}$	@ 7A, Pulse, $T_J = -55\text{ °C}$	0.74	
	$V_{F15}$	@ 10A, Pulse, $T_J = -55\text{ °C}$	0.80	
Max. Reverse Current (per leg)	$I_{R1}$	@ $V_R = 100V$ , Pulse, $T_J = 25\text{ °C}$	0.2	mA
	$I_{R2}$	@ $V_R = 100V$ , Pulse, $T_J = 125\text{ °C}$	20	mA
Max. Junction Capacitance (per leg)	$C_T$	@ $V_R = 5V$ , $T_C = 25\text{ °C}$ $f_{SIG} = 1MHz$ , $V_{SIG} = 50mV$ (p-p)	600	pF

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**Mechanical Dimensions: in Inches**



**SMD-0.2**

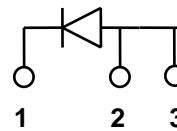
**PINOUT TABLE**

DEVICE TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE

**ORDERING INFORMATION**

PART NUMBER	LID CONNECTION
SHDT187284	Floating
SHDT187284J1	PIN 1
SHDT187284J2	PIN 2
SHDT187284J3	PIN 3

**SINGLE**



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